

## Silicon NPN Power Transistors

## 2SC2485

**DESCRIPTION**

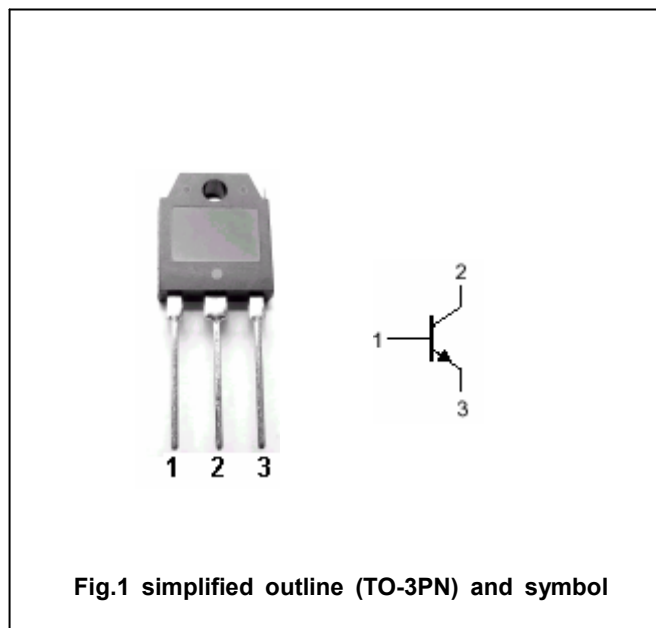
- With TO-3PN package
- Complement to type 2SA1061
- High collector power dissipation

**APPLICATIONS**

- High power audio frequency amplifier

**PINNING**

| PIN | DESCRIPTION                          |
|-----|--------------------------------------|
| 1   | Base                                 |
| 2   | Collector;connected to mounting base |
| 3   | Emitter                              |

**Absolute maximum ratings(Ta=25℃)**

| SYMBOL    | PARAMETER                   | CONDITIONS             | MAX     | UNIT |
|-----------|-----------------------------|------------------------|---------|------|
| $V_{CBO}$ | Collector-base voltage      | Open emitter           | 100     | V    |
| $V_{CEO}$ | Collector-emitter voltage   | Open base              | 100     | V    |
| $V_{EBO}$ | Emitter-base voltage        | Open collector         | 5       | V    |
| $I_C$     | Collector current (DC)      |                        | 6       | A    |
| $I_{CP}$  | Collector current (Pulse)   |                        | 10      | A    |
| $P_C$     | Collector power dissipation | $T_C=25^\circ\text{C}$ | 70      | W    |
| $T_j$     | Junction temperature        |                        | 150     | ℃    |
| $T_{stg}$ | Storage temperature         |                        | -55~150 | ℃    |

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## CHARACTERISTICS

Tj=25°C unless otherwise specified

| SYMBOL        | PARAMETER                            | CONDITIONS             | MIN | TYP. | MAX | UNIT    |
|---------------|--------------------------------------|------------------------|-----|------|-----|---------|
| $V_{(BR)CEO}$ | Collector-emitter breakdown voltage  | $I_C=10mA ; I_B=0$     | 100 |      |     | V       |
| $V_{CEsat}$   | Collector-emitter saturation voltage | $I_C=4A ; I_B=0.4A$    |     |      | 2.0 | V       |
| $V_{BE}$      | Base-emitter on voltage              | $I_C=4A ; V_{CE}=5V$   |     |      | 1.8 | V       |
| $I_{CBO}$     | Collector cut-off current            | $V_{CB}=100V ; I_E=0$  |     |      | 50  | $\mu A$ |
| $I_{EBO}$     | Emitter cut-off current              | $V_{EB}=3V ; I_C=0$    |     |      | 50  | $\mu A$ |
| $h_{FE-1}$    | DC current gain                      | $I_C=0.2A ; V_{CE}=5V$ | 20  |      |     |         |
| $h_{FE-2}$    | DC current gain                      | $I_C=1A ; V_{CE}=5V$   | 40  |      | 200 |         |
| $h_{FE-3}$    | DC current gain                      | $I_C=4A ; V_{CE}=5V$   | 20  |      |     |         |
| $f_T$         | Transition frequency                 | $I_C=0.5A ; V_{CE}=5V$ |     | 20   |     | MHz     |

◆  $h_{FE-2}$  Classifications

| R     | Q      | P       |
|-------|--------|---------|
| 40-80 | 60-120 | 100-200 |

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[illegible]